DESCRIPTION

The SPN3456 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

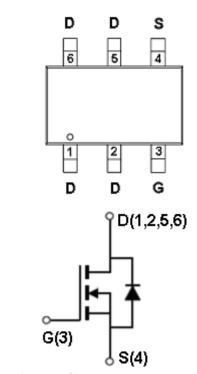
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

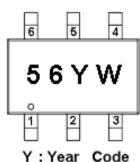
FEATURES

- 30V/6.0A,RDS(ON)= $40m\Omega$ @VGS=10V
- 30V/5.0A, RDS(ON)= $50m\Omega(@VGS=4.5V$
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOT-23-6L package design

PIN CONFIGURATION(SOT-23-6L)



PART MARKING



W : Week Code

PIN DESCRIPTION						
Pin	Symbol	Description				
1	D	Drain				
2	D	Drain				
3	G	Gate				
4	S	Source				
5	D	Drain				
6	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking		
SPN3456S26RGB	SOT-23-6L	56		

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN3456S26RGB : Tape Reel ; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±20	V	
Cartings Dain Computer 1500C)	Ta=25°C	Τ_	6.0		
Continuous Drain Current(T _J =150°C)	Ta=70°C	- Id	5.0	A	
Pulsed Drain Current		Ірм	30	A	
Continuous Source Current(Diode Conduction)		Is	1.7	A	
Down Dissingtion	Ta=25°C	Dra	2.0	W	
Power Dissipation	Ta=70°C	PD	1.3	W	
Operating Junction Temperature		TJ	150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	90	°C/W	

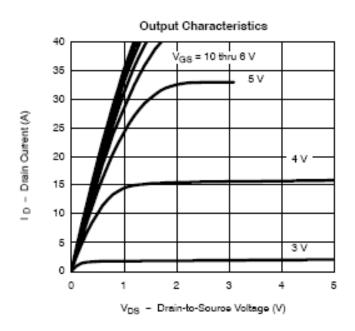


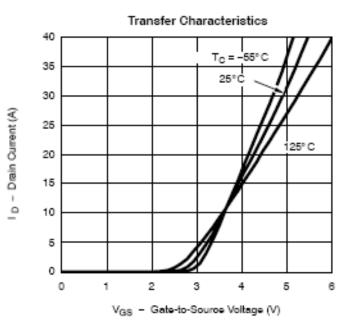
ELECTRICAL CHARACTERISTICS

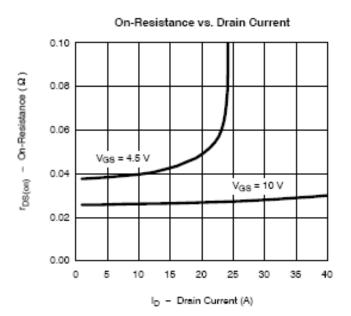
(TA=25°C Unless otherwise noted)

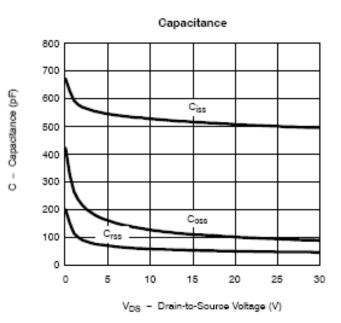
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	1.0		3.0] V
Gate Leakage Current	Igss	V _{DS} =0V,V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	IDSS	VDS=24V,VGS=1.0V VDS=24V,VGS=0.0V TJ=55°C			1 10	uA
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 4.5V$	10			A
Drain-Source On-Resistance	RDS(on)	VGS = 10V,ID=6.0A VGS =4.5V,ID=5.0A		0.030 0.040	0.040 0.050	Ω
Forward Transconductance	gfs	VDS=4.5V,ID=5.4A		12		S
Diode Forward Voltage	Vsd	Is=1.7A,VGS=0V		0.8	1.2	V
Dynamic						
Total Gate Charge	Qg	V _{DS} =15V _{GS} =10V -I _D =6.7A		10	18	nC
Gate-Source Charge	Qgs			1.6		
Gate-Drain Charge	Qgd	1D-0.7A		3.2		
Input Capacitance	Ciss	V _{DS} =15V _{GS} =0V f=1MHz		450		pF
Output Capacitance	Coss			240		
Reverse Transfer Capacitance	Crss			38		
Turn-On Time	td(on)			7	15	nS
	tr	VDD=15RL=15		10	20	
Turn-Off Time	td(off)	ID=1.0A,VGEN=10 RG=6Ω		20	40	
	tf			11	20	

TYPICAL CHARACTERISTICS

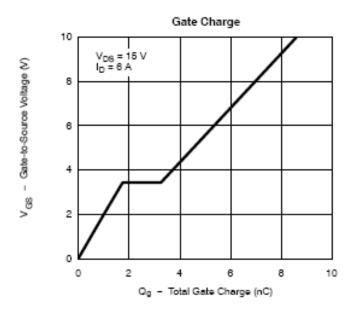


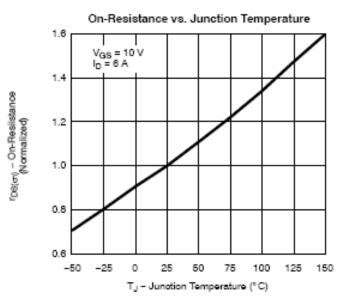


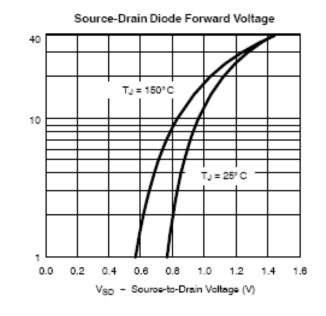




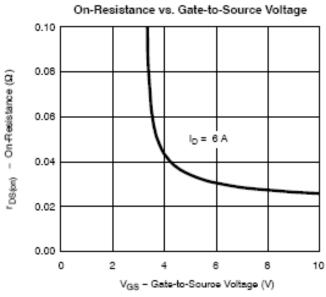
TYPICAL CHARACTERISTICS



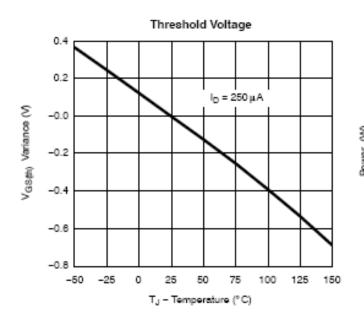


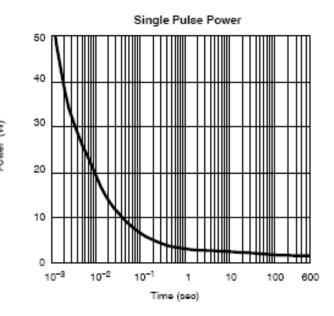


1s - Source Current (A)

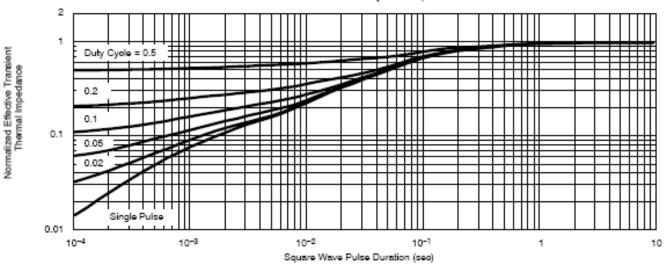


TYPICAL CHARACTERISTICS





Normalized Thermal Transient Impedance, Junction-to-Foot



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